

View Online at <https://aerobasegroup.com/nsn/5961-01-514-2181>

**Inclosure Material:**

Metal

**Overall Length:**

1.200 inches

**Overall Height:**

0.200 inches

**Overall Width:**

0.550 inches

**Mounting Facility Quantity:**

2

**Mounting Method:**

Slot

**Features Provided:**

Low noise

**Semiconductor Material:**

Silicon

**Voltage Rating In Volts Per Characteristic:**

70.0 drain to gate voltage and 70.0 drain to source voltage and 30.0 gate to source voltage

**Current Rating Per Characteristic:**

16.00 amperes source cutoff current of standard range

**Power Rating Per Characteristic:**

350.0 watts small-signal input power, common-collector absolute

**Product Name:**

Silicon rf power, vdmoss transistor

**Special Features:**

8gold metalized; package style - ah; high efficiency; linear; high gain; junction temperature plus 200.0 degrees c; storage temperature minus 65.0 to plus 150.0 degrees c; designed specifically for broadband radio frequency (rf) applications

**Terminal Type And Quantity:**

2 tab, solder lug

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

A110a0